

Description

The IPD160N04LG uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

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TO-252-2L

General Features

V_{DS} = 40V I_D =30A

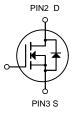
 $R_{DS(ON)}$ < 22m Ω @ V_{GS} =10V

Application

Battery protection

Load switch

Uninterruptible power supply



N-Channel MOSFET

Package Marking and Ordering Information

| Product ID | Pack | Brand | Qty(PCS) |
|-------------|-----------|------------|----------|
| IPD160N04LG | TO-252-2L | HXY MOSFET | 2500 |

Absolute Maximum Ratings (T_c =25°C unless otherwise noted)

| Symbol | Parameter | Rating | Units | |
|---------------------------------------|---|------------|-------|--|
| Vos | Drain-Source Voltage | 40 | V | |
| Vgs | Gate-Source Voltage | ±20 | V | |
| I _D @T _C =25°C | Continuous Drain Current, V _{GS} @ 10V ¹ | 30 | А | |
| I _D @T _C =100°C | Continuous Drain Current, V _{GS} @ 10V ¹ | 15 | А | |
| Ідм | Pulsed Drain Current ² | 40 | А | |
| EAS | Single Pulse Avalanche Energy³ | 17.1 | mJ | |
| las | Avalanche Current | 10 | А | |
| P _D @T _C =25°C | Total Power Dissipation ⁴ | 4 | W | |
| Тѕтс | Storage Temperature Range | -55 to 150 | °C | |
| TJ | Operating Junction Temperature Range | -55 to 150 | °C | |
| $R_{	heta JA}$ | Thermal Resistance Junction-ambient (Steady State) ¹ | 62 | °C/W | |
| R _θ Jc | Thermal Resistance Junction-Case ¹ | 2.8 | °C/W | |



N-Channel Electrical Characteristics (TJ=25°C unless otherwise specified)

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|----------------------|------------------------------------|---|--------------|------|------|-------|
| V _{(BR)DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V, I _D =250μA | 40 | - | - | V |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} =40V, V _{GS} =0V | - | - | 1.0 | μA |
| I _{GSS} | Gate to Body Leakage Current | V _{DS} =0V, V _{GS} =±20V | - | - | ±100 | nA |
| $V_{GS(th)}$ | Gate Threshold Voltage | $V_{DS}=V_{GS}$, $I_{D}=250\mu A$ | 1.0 | 1.5 | 2.5 | V |
| Ъ | Static Drain-Source on-Resistance | V _{GS} =10V, I _D =8A | - | 18 | 22 | mΩ |
| $R_{DS(on)}$ | | V _{GS} =4.5V, I _D =5A | - | 25 | 35 | mΩ |
| C _{iss} | Input Capacitance | \\ -20\\ \\ -0\\ | - | 633 | - | pF |
| Coss | Output Capacitance | V _{DS} =20V, V _{GS} =0V, f=1.0MHz | - | 67 | - | pF |
| Crss | Reverse Transfer Capacitance | - 1-1.0ivii iZ | - | 58 | - | pF |
| Qg | Total Gate Charge | \/ OO\/ OA | - | 12 | - | nC |
| Q _{gs} | Gate-Source Charge | V _{DS} =20V, I _D =8A, V _{GS} =10V | - | 3.2 | - | nC |
| Q_{gd} | Gate-Drain("Miller") Charge | VGS-10V | - | 3.1 | - | nC |
| t _{d(on)} | Turn-on Delay Time | | - | 4 | - | ns |
| t _r | Turn-on Rise Time | V_{DD} = 20V, R_L =2.5 Ω | - | 3 | - | ns |
| t _{d(off)} | Turn-off Delay Time | V_{GS} =10V, R_{REN} =3 Ω | - | 15 | - | ns |
| t _f | Turn-off Fall Time | | - | 2 | - | ns |
| 1 | Maximum Continuous Drain to Source | e Diode Forward | iode Forward | | 30 | ۸ |
| Is | Current | - - | | - | 30 | Α |
| I _{SM} | Maximum Pulsed Drain to Source Did | ode Forward Current | - | - | 40 | Α |
| V | Drain to Source Diode Forward | V _{GS} =0V, I _S = 8A | | - | 1.2 | V |
| V_{SD} | Voltage | VGS-UV, IS- OA | - | | | |

Notes:1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

3. Pulse Test: Pulse Width≤300µs, Duty Cycle≤2%



Typical Performance Charcteristics

Figure1: Output Characteristics

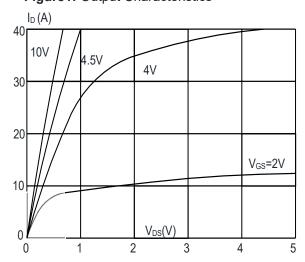


Figure 3:On-resistance vs. Drain Current

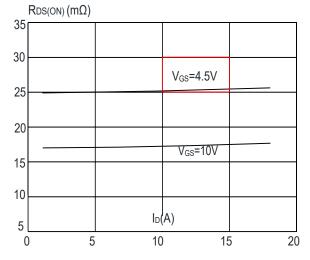


Figure 5: Gate Charge Characteristics

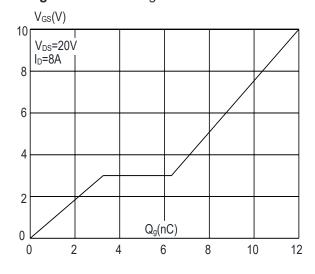


Figure 2: Typical Transfer Characteristics

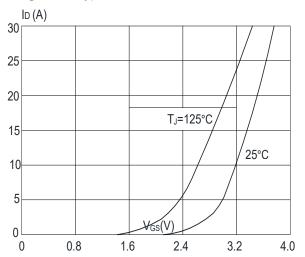


Figure 4: Body Diode Characteristics

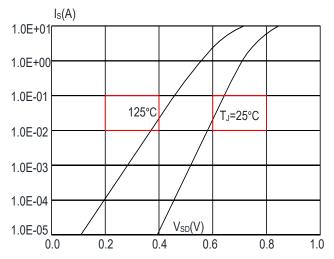


Figure 6: Capacitance Characteristics

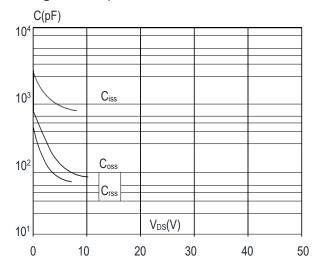




Figure 7: Normalized Breakdown Voltage vs. Junction Temperature

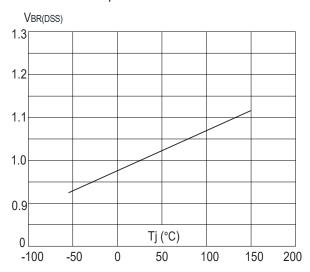


Figure 9: Maximum Safe Operating Area

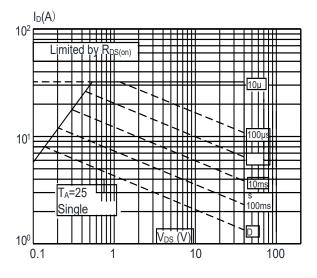


Figure.11: Maximum Effective
Transient Thermal Impedance, Junction-to-Ambient

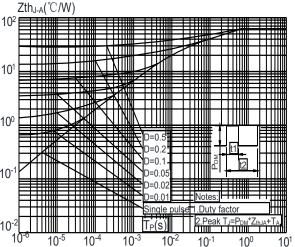


Figure 8: Normalized on Resistance vs. Junction Temperature

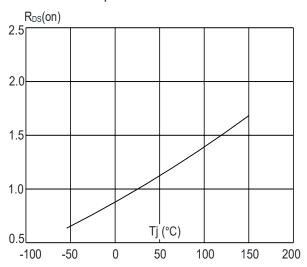
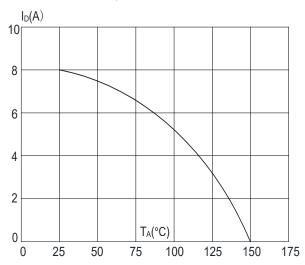
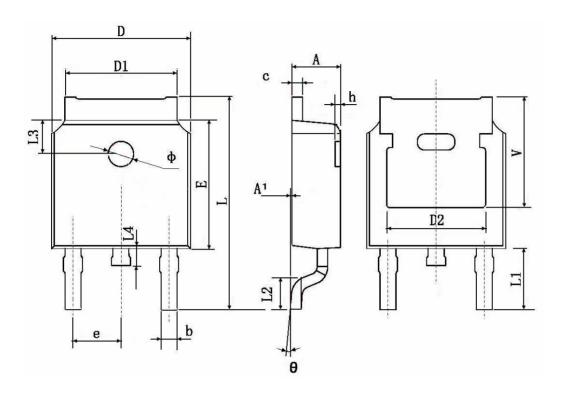


Figure 10: Maximum Continuous Drain Current vs. Ambient Temperature





TO-252-2L Package Information



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | | |
|--------|---------------------------|------------|----------------------|------------|--|
| | Min. | Max. | Min. | Max. | |
| А | 2.200 | 2.400 | 0.087 | 0.094 | |
| A1 | 0.000 | 0.127 | 0.000 | 0.005 | |
| b | 0.660 | 0.860 | 0.026 | 0.034 | |
| С | 0.460 | 0.580 | 0.018 | 0.023 | |
| D | 6.500 | 6.700 | 0.256 | 0.264 | |
| D1 | 5.100 | 5.460 | 0.201 | 0.215 | |
| D2 | 0.483 TYP. | | 0.190 TYP. | | |
| Е | 6.000 | 6.200 | 0.236 | 0.244 | |
| е | 2.186 | 2.386 | 0.086 | 0.094 | |
| L | 9.800 | 10.400 | 0.386 | 0.409 | |
| L1 | 2.900 | 2.900 TYP. | | 0.114 TYP. | |
| L2 | 1.400 | 1.700 | 0.055 | 0.067 | |
| L3 | 1.600 | TYP. | 0.063 TYP. | | |
| L4 | 0.600 | 1.000 | 0.024 | 0.039 | |
| Ф | 1.100 | 1.300 | 0.043 | 0.051 | |
| θ | 0° | 8° | 0° | 8° | |
| h | 0.000 | 0.300 | 0.000 | 0.012 | |
| V | 5.350 TYP. | | 0.211 TYP. | | |



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